

Supporting Information

Heterostructural MoS₂/NiS nanoflowers via precise interface modification for enhancing electrocatalytic hydrogen evolution

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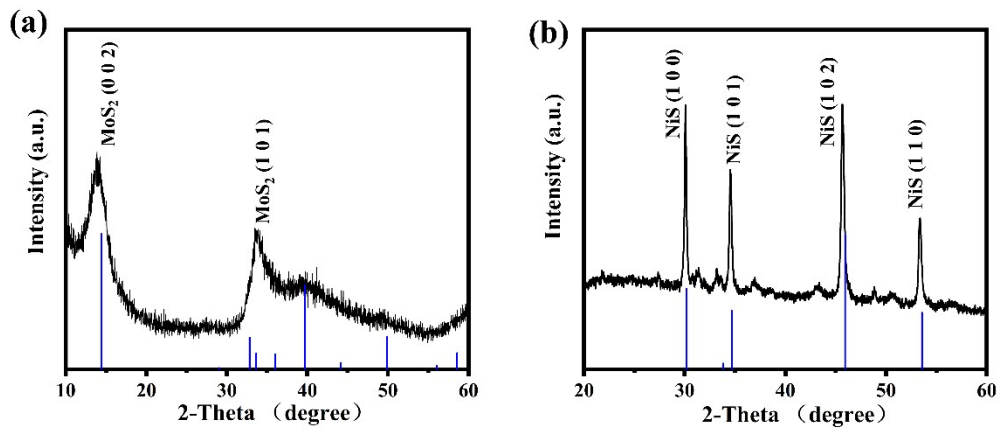


Figure S1 (a) The XRD patterns of pure MoS₂. (b) The XRD patterns of pure NiS nanostructures.

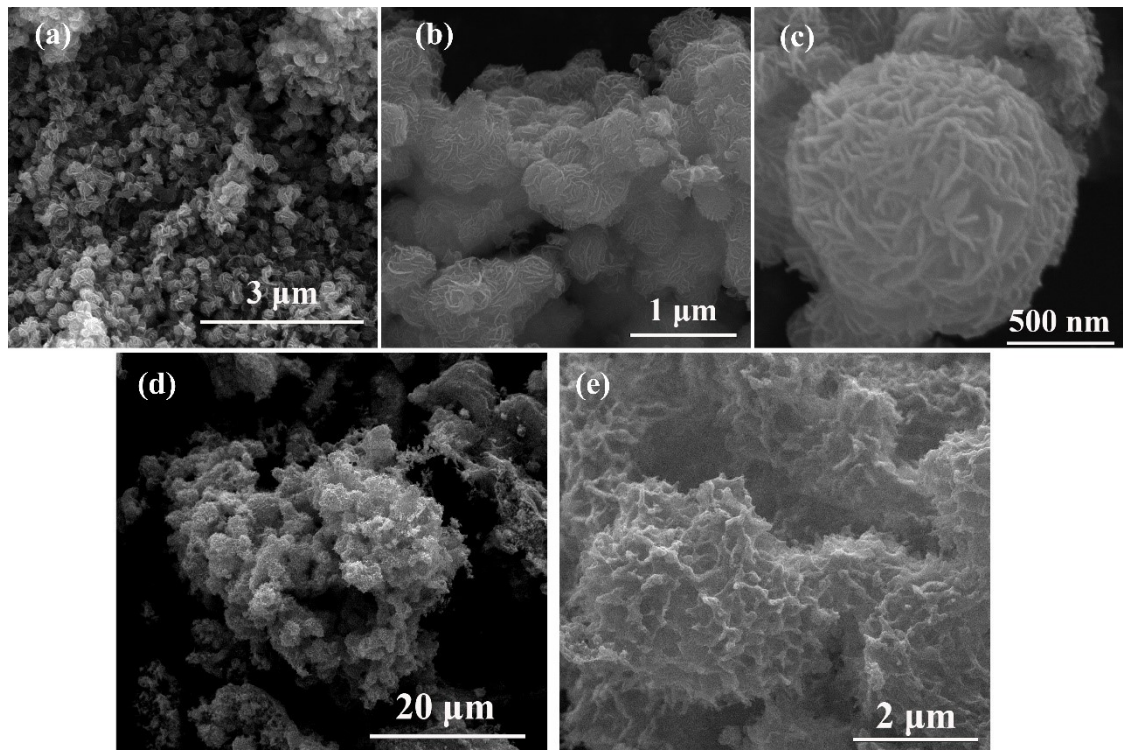


Figure S2 Different scale bar SEM images of the MoS₂ flowers like heterostructures (a) 3 μm, (b) 1 μm, (c) 500 nm. Different scale bar SEM images of the NiS nanostructures (d) 20 μm, (e) 2 μm.

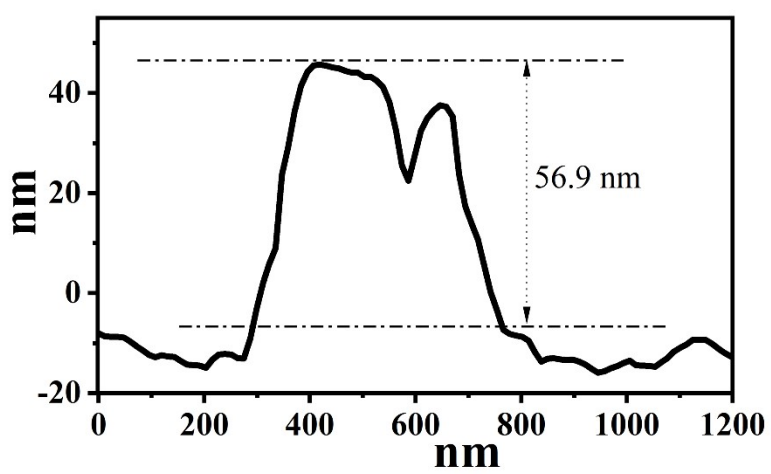
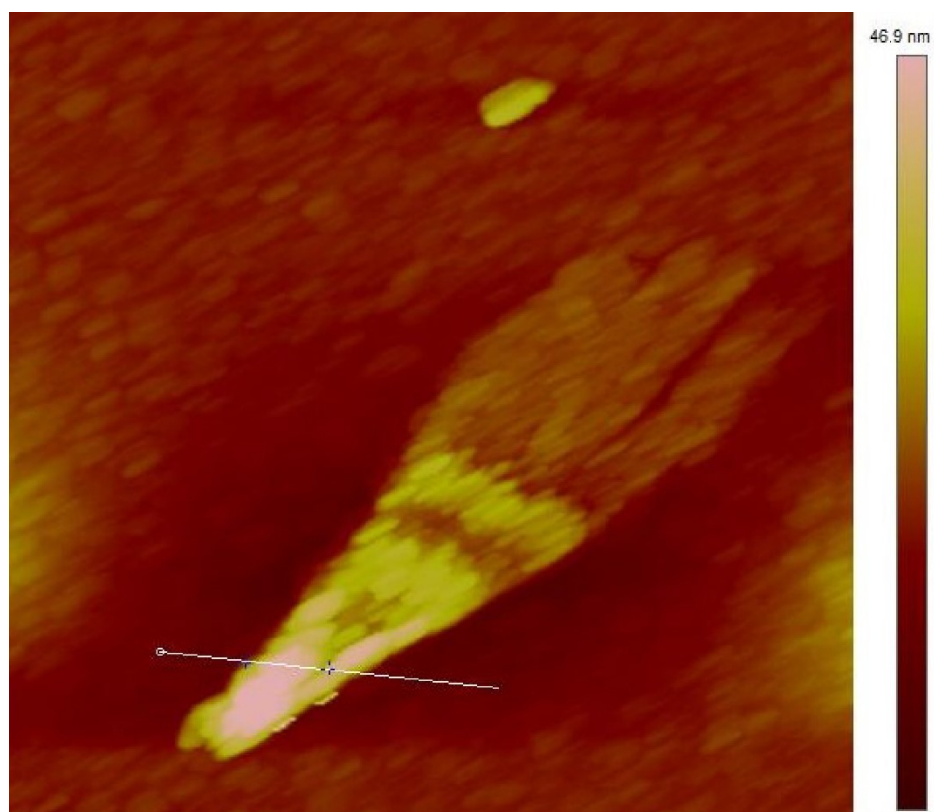


Figure S3 AFM image (top) and its height profile (bottom) along the white line of the MoS₂.

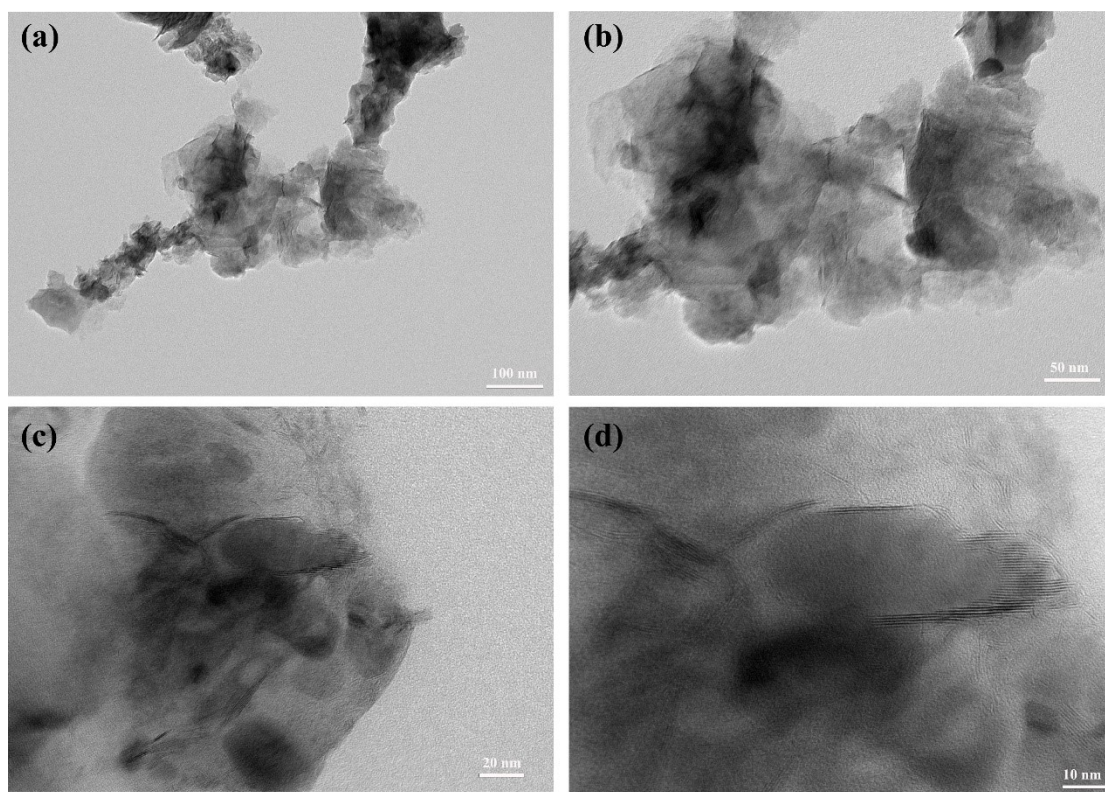


Figure S4 Different scale bar TEM images of the MoS₂/NiS flowers like heterostructures (a) 100 nm, (b) 50 nm, (c) 20 nm, (d) 10 nm.

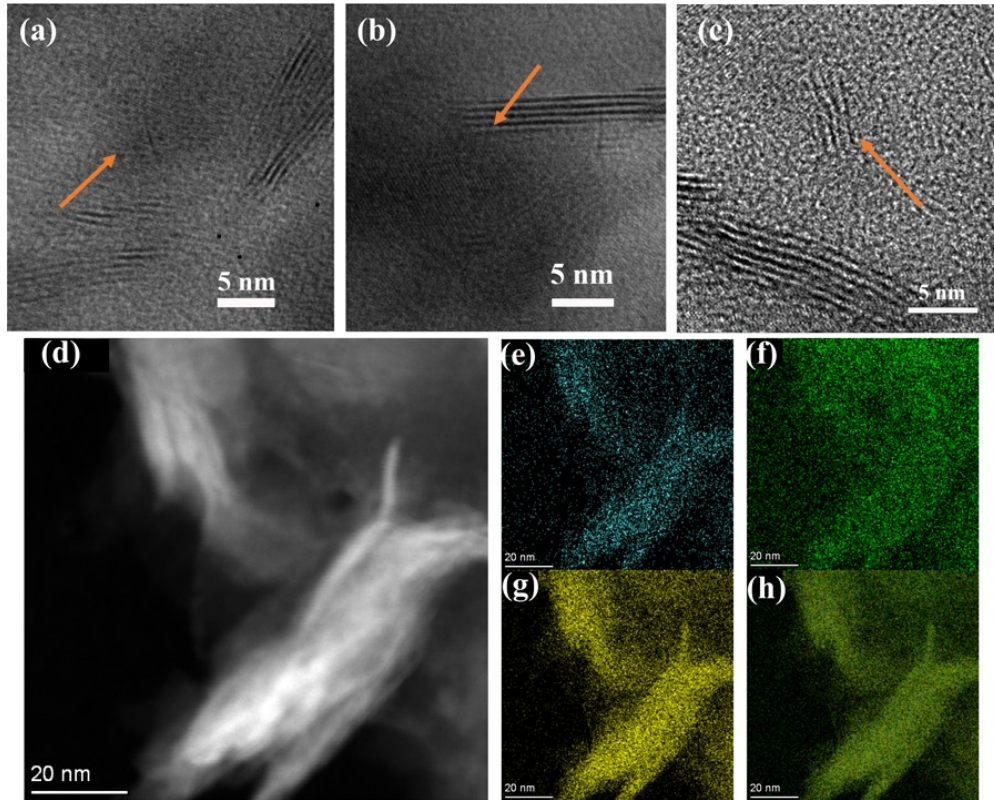


Figure S5 (a-c) The interface of the constructed MoS₂/NiS heterostructures. (d) The high-angle annular dark-field (HAADF) STEM image of MoS₂/NiS heterostructures and corresponding elemental mapping images of (e) Mo, (f) Ni, (g) S, and (h) overlap of the Mo, Ni, S.

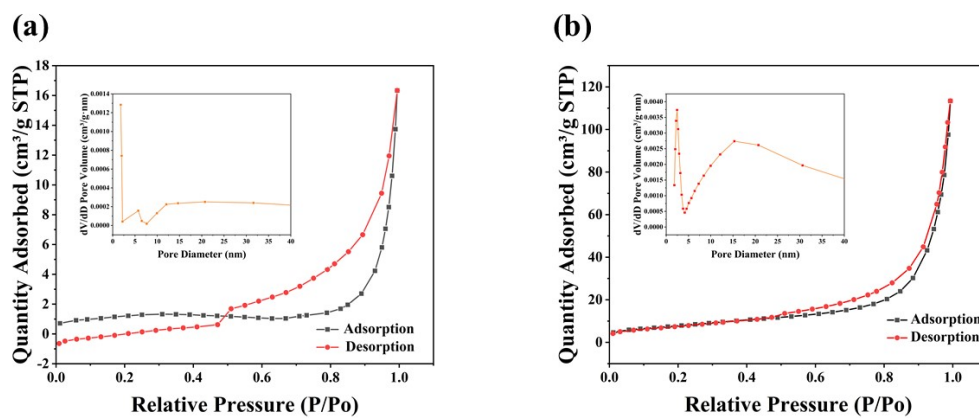


Figure S6 N₂ adsorption-desorption isotherm of (a) MoS₂, (b) MoS₂/NiS flowers like heterostructures, inset is the corresponding pore size distribution curve.

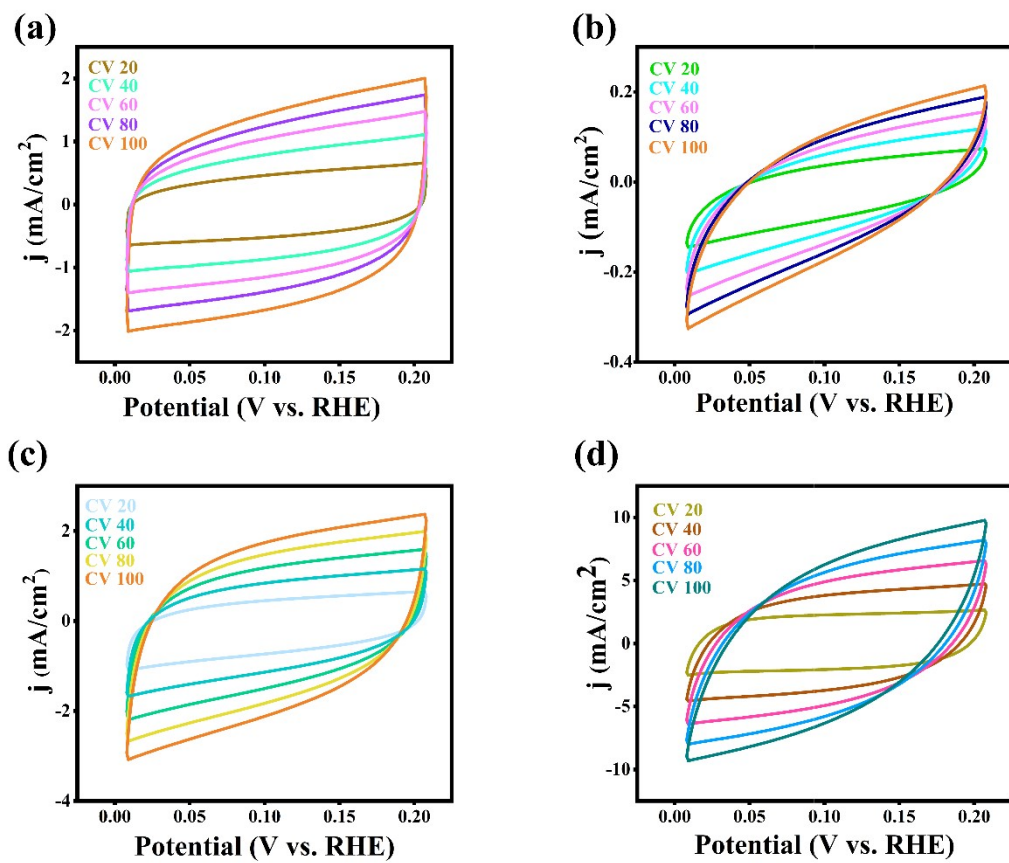


Figure S7 CV curves of (a) MoS₂, (b) NiS, (c) MoS₂/NiS flowers like heterostructures and (d) Pt/C.

At scan rates of 20, 40, 60, 80, 100 mV s⁻¹ in 1.0 M KOH, respectively.

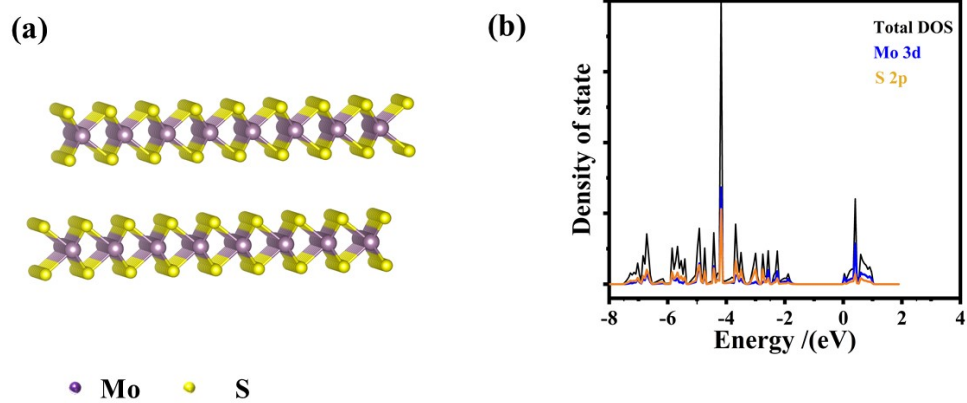


Figure S8 (a) MoS₂ (0 0 2) plane, (b) and the projected density of states of MoS₂ (0 0 2) plane.

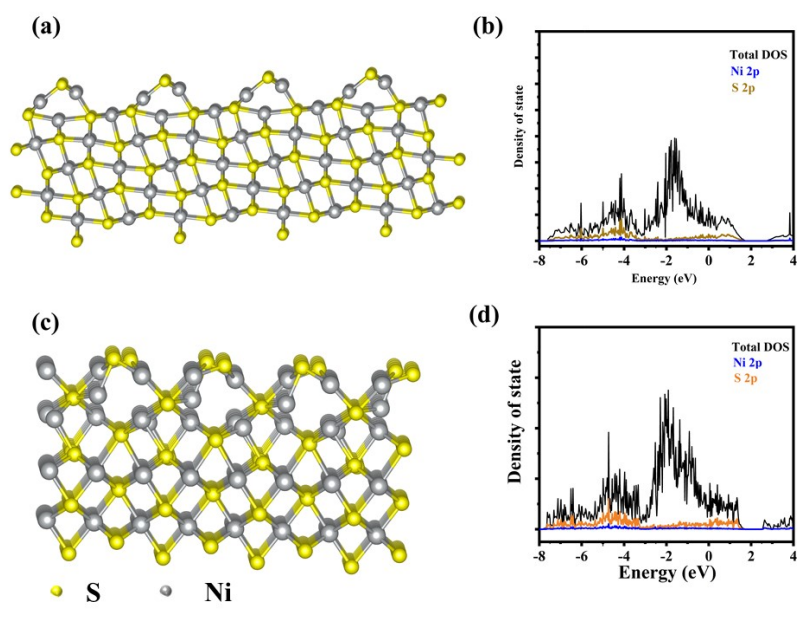


Figure S9 (a) NiS (1 0 2) plane, (b) and the projected density of states of NiS (1 0 2) plane, (c) NiS (1 0 0) plane, (d) and the projected density of states of NiS (1 0 0) plane.

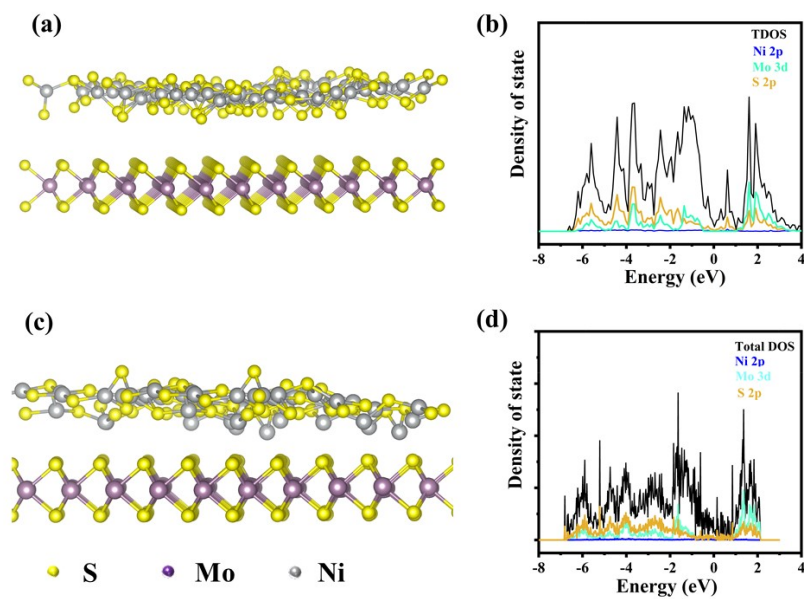


Figure S10 (a) Heterostructures constructed by using MoS₂ (0 0 2) crystal surface and NiS (1 0 0) crystal surface. (b) And the projected density of states of MoS₂/NiS heterostructures. (c) Heterostructures constructed by using MoS₂ (0 0 2) crystal surface and NiS (1 0 2) crystal surface, (d) and the projected density of states of MoS₂/NiS heterostructures.

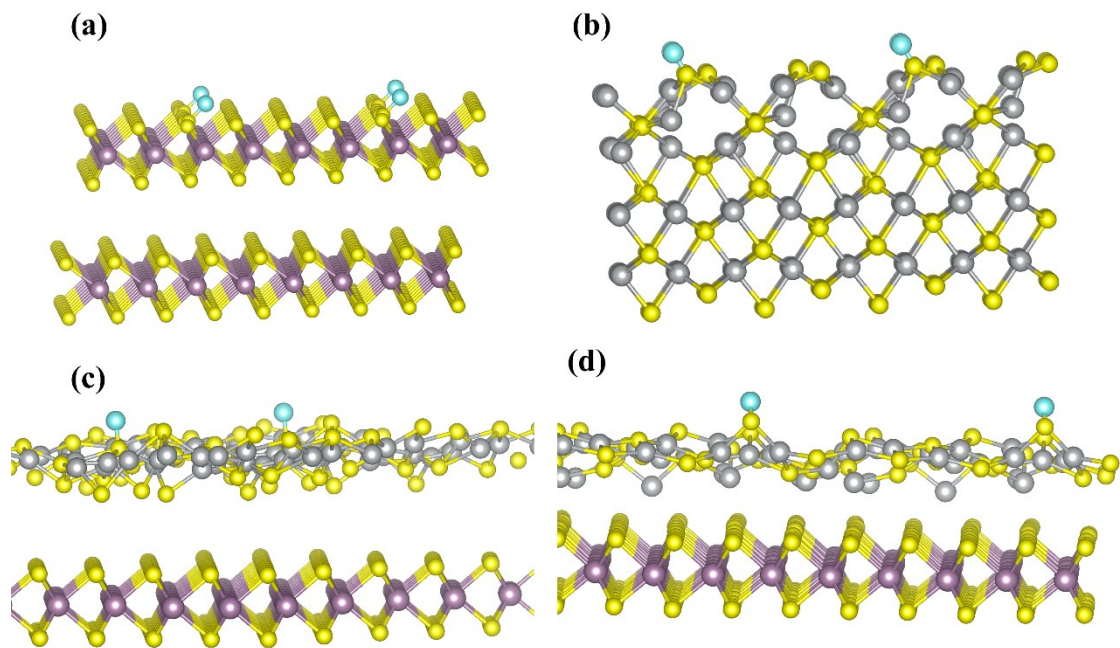


Figure S11 Hydrogen atoms adsorb on different DFT chemisorption models. (a) Hydrogen atoms adsorb on the MoS₂ (0 0 2) basal plane sites, (b) hydrogen atoms adsorb on the NiS (1 0 0) plane, (c) hydrogen atoms adsorb on the heterogeneous structure constructed by using MoS₂ (0 0 2) crystal surface and NiS (1 0 0) crystal surface, (d) hydrogen atoms adsorb on the heterogeneous structure constructed by using MoS₂ (0 0 2) crystal surface and NiS (1 0 2) crystal surface.

DFT models	E₀ (eV)	ΔG (eV)	ΔG_{H*} (eV)
NiS (1 0 0) _slab	-633.777	0	
NiS (1 0 0) _H	-636.670	0.216	0.703
MoS ₂ (0 0 2) _slab	-1395.438	0	
MoS ₂ (0 0 2) _H	-1397.132	0.173	1.859
MoS ₂ (1 0 0) _slab	-662.197	0	
MoS ₂ (1 0 0) _H	-666.361	0.231	-0.553
MoS ₂ /NiS (1 0 0) _slab	-1032.172	0	
MoS ₂ /NiS (1 0 0) _H	-1035.277	0.220	0.525
MoS ₂ /NiS (1 0 2) _slab	-1062.910	0	
MoS ₂ /NiS (1 0 2) _H	-1066.030	0.222	0.482

Table S1 The specific values of the surface energy of different slabs and the surface energy of hydrogen adsorption models.

Samples	η_{10} (mV)	Tafel (mV dec ⁻¹)	Ref.
1T-2H Cr _x -MoS ₂ Ultrathin Nanosheets	200	41.6	1
Al-MoS ₂	198	134	2
VNMS	122	57	3
MoS ₂ QDs/NiO NSs	186	73.5	4
Co-Ni-P/MoS ₂	116	41	5
K-G _{4.0} T _{2.0} Mo _{1.0}	173	66.4	6
MoS ₂ /NiS-Ni ₃ S ₂ /NF	181	70	7
MoS ₂ /Ni ₃ S ₂ foam	190	65.6	8
Cu ₉ S ₅ @MoS ₂ /CNFs	114	199	9
MoNiCNTs-4	238	84	10
Ni ₂ P/MoS ₂	149	69.5	11
NCN-CoMoS-700	126	74.1	12
S-MoS ₂ @C	155	78	13
MoS ₂ /FNS/FeNi foam	122	45.1	14
Single-layer MoS ₂	185	45	15
MoS ₂ /Ni ₃ S ₂ heterostructures	110	83	16
MoS₂/NiS heterostructures	158	128.1	This work

Table S2. Comparison of HER performance of electrocatalysts reported in different literatures in alkaline solution.

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